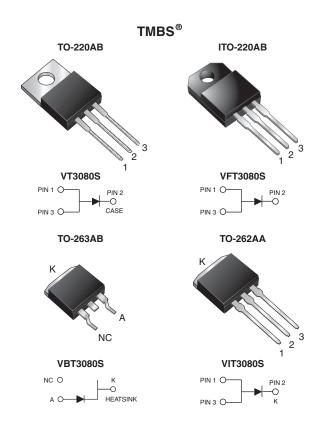
Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.39$ V at $I_F = 5$ A



www.vishay.com

'ISHA'

PRIMARY CHARACTERISTICS						
I _{F(AV)}	30 A					
V _{RRM}	80 V					
I _{FSM}	200 A					
V _F at I _F = 30 A	0.73 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, TO-263AB, TO-262AA					
Circuit configuration	Single					

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)



- ROHS COMPLIANT
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	L VT3080S VFT3080S VBT3080S VIT3080S				UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	80				V	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	30				Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	200				А	
Non-repetitive avalanche energy at T_J = 25 °C, L = 100 mH	E _{AS}	250			mJ		
Peak repetitive reverse current at t_p = 2 µs, 1 kHz, T_J = 38 °C ± 2 °C	I _{RRM}	1.0			А		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			V		
Operating junction and storage temperature range	T _J , T _{STG}		-55 to	o +150		°C	

Revision: 16-Mar-18

1

Document Number: 89169

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



www.vishay.com

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	TEST CONDITIONS		CONDITIONS SYMBOL		MAX.	UNIT		
Breakdown voltage	I _R = 1.0 mA	T _A = 25 °C	V _{BR}	80 (minimum)	-	V		
Instantaneous forward voltage	$I_F = 5 A$	T _A = 25 °C	- V _F (1)	0.47	-	V		
	I _F = 15 A			0.61	-			
	I _F = 30 A	-		0.82	0.95			
	$I_F = 5 A$	T _A = 125 °C		0.39	-			
	I _F = 15 A			0.57	-			
	I _F = 30 A			0.73	0.82			
Reverse current	V _B = 80 V	T _A = 25 °C	1 (2)	70	1000	μA		
	$V_{R} = 80 V$ $T_{A} = 125 °C$	I _R ⁽²⁾	23	45	mA			

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

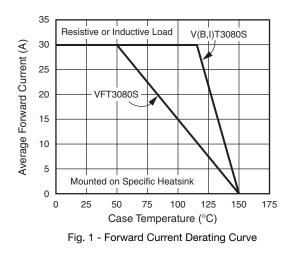
 $^{(2)}$ Pulse test: Pulse width $\leq 40\mbox{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	SYMBOL	VT3080S	VFT3080S	VBT3080S	VIT3080S	UNIT	
Typical thermal resistance	$R_{ ext{ heta}JC}$	1.5	5.0	1.5	1.5	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	VT3080S-E3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VFT3080S-E3/4W	1.75	4W	50/tube	Tube			
TO-263AB	VBT3080S-E3/4W	1.37	4W	50/tube	Tube			
TO-263AB	VBT3080S-E3/8W	1.37	8W	800/reel	Tape and reel			
TO-262AA	VIT3080S-E3/4W	1.46	4W	50/tube	Tube			

Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)



www.vishay.com

ISHA

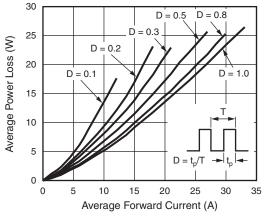


Fig. 2 - Forward Power Loss Characteristics

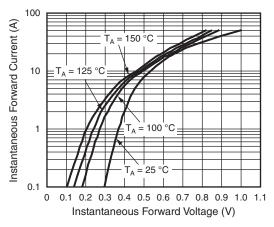
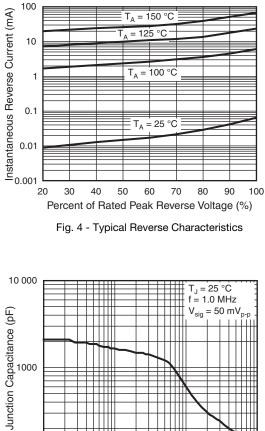


Fig. 3 - Typical Instantaneous Forward Characteristics



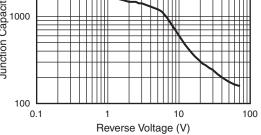


Fig. 5 - Typical Junction Capacitance

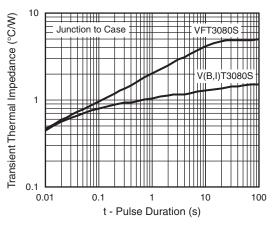


Fig. 6 - Typical Transient Thermal Impedance

Revision: 16-Mar-18

3

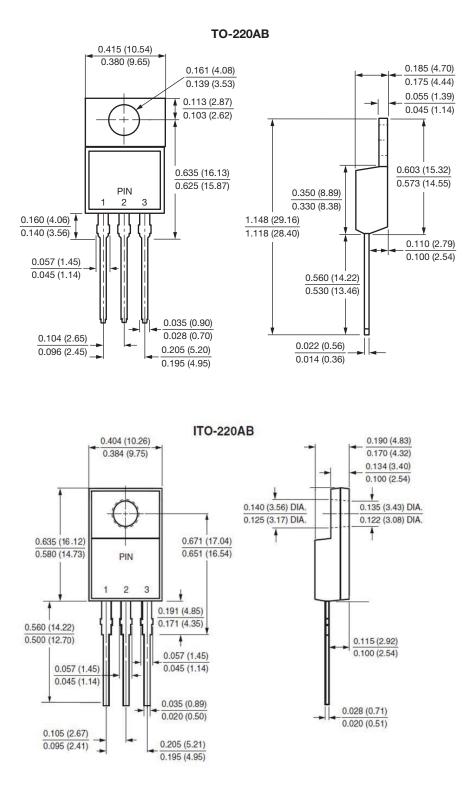
For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

www.vishay.com

VISHAY



 Revision: 16-Mar-18
 4
 Document Number: 89169

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

Downloaded from Arrow.com.



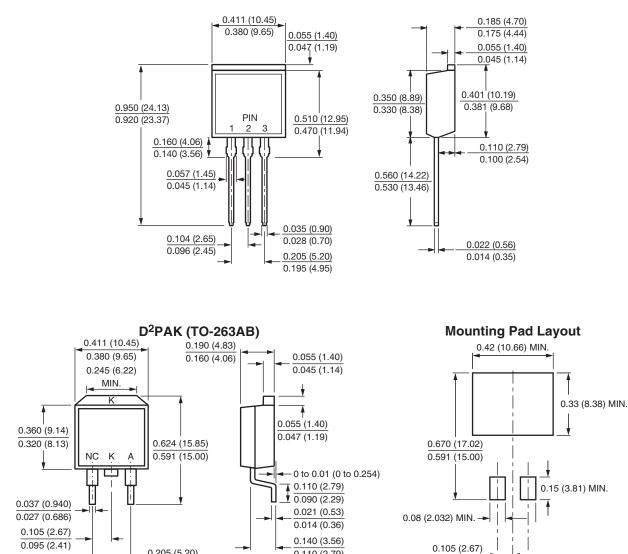
www.vishay.com

0.205 (5.20)

0.195 (4.95)

Vishay General Semiconductor

TO-262AA



0.110 (2.79)

0.095 (2.41)



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.